TPS7B4255-Q1
Automotive, 70-mA, 40-V, Voltage-Tracking LDO With 5-mV Tracking Tolerance

1 Features

- AEC-Q100 qualified for automotive applications:
  - Temperature grade 1: –40°C to +125°C, T_A
  - Junction temperature: –40°C to +150°C, T_J
- Wide input operating voltage range (3 V to 40 V):
  - Absolute maximum input voltage range: –40 V to +45 V
- Wide output voltage range: 2 V to 40 V
- Maximum output current: 70 mA
- Very-tight, output-tracking tolerance: 5 mV (max)
- Low dropout voltage: 500 mV (max) at 70 mA
- Combined reference and enable functionalities
- Low quiescent current at light load: 35 µA
- Wide C_{OUT} and ESR range:
  - Stable with 1-µF to 200-µF ceramic output capacitor, 1-mΩ to 3-Ω ESR
- Integrated protection features:
  - Reverse current protection
  - Reverse polarity protection
  - Overtemperature protection
  - Protection against output short-circuit to ground and supply
- Available in two 5-pin SOT-23 packages:
  - Standard SOT-23 (DBV)
  - Thermally enhanced SOT-23 (DYB)

2 Applications

- Powertrain pressure sensors
- Powertrain temperature sensors
- Powertrain exhaust sensors
- Powertrain fluid concentration sensors
- Body control modules (BCM)

3 Description

The TPS7B4255-Q1 is a low-dropout (LDO) voltage-tracking regulator, with high tracking accuracy and excellent load and line transient response. The device is available in two 5-pin, SOT-23 packages (DBV and DYB). The TPS7B4255-Q1 is designed to supply off-board sensors in automotive applications such as powertrain systems. Because the risk of failure in cables that deliver off-board power is high, the device comes with integrated protection features against fault conditions such as reverse current (short to battery), reverse polarity, output short to ground (current limit), and overtemperature (thermal shutdown). The device is designed to handle a 45-V (absolute maximum) input voltage and survive the automotive load dump transient conditions.

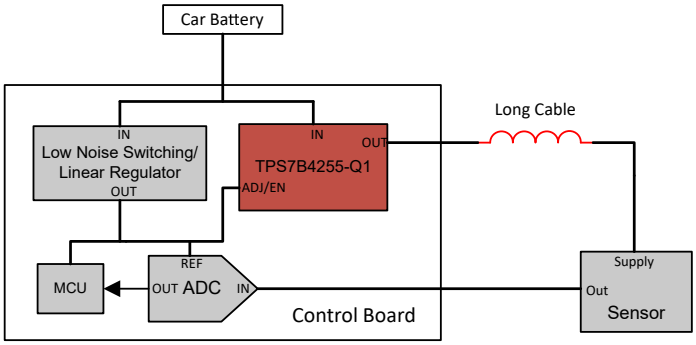
A reference voltage applied at the ADJ/EN pin is effectively tracked at the OUT pin with very tight tolerance for loads up to 70 mA. The TPS7B4255-Q1 can therefore deliver the power-supply voltage to the off-board sensors with high precision, which can help improve the reliability and accuracy of measurements made using ratiometric sensors.

By setting the ADJ/EN input pin low, the TPS7B4255-Q1 switches to standby mode and reduces the quiescent current of the LDO to less than 3.25 µA.

Package Information

PART NUMBER	PACKAGE(1)	PACKAGE SIZE(2)
TPS7B4255-Q1	DBV (SOT-23, 5)	2.9 mm × 2.8 mm
	DYB (SOT-23, 5)	2.93 mm × 2.7 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.
(2) The package size (length × width) is a nominal value and includes pins, where applicable.



Typical Application

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision * (June 2022) to Revision A (August 2023)	Page
• Changed document status from *Advance Information* to *Production Data*	1

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5 Pin Configuration and Functions

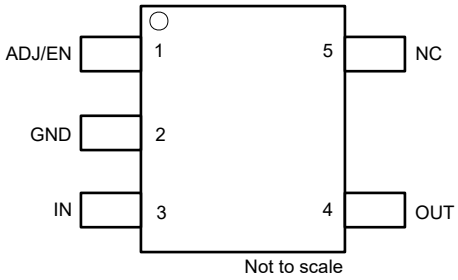


Figure 5-1. DBV Package, 5-Pin SOT-23 (Top View)

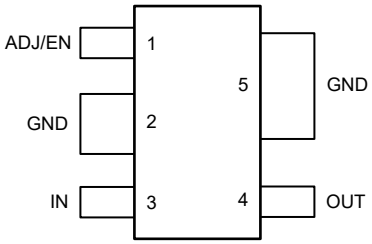


Figure 5-2. DYB Package, 5-Pin SOT-23 (Top View)

Table 5-1. Pin Functions

PIN			TYPE	DESCRIPTION
NAME	DBV	DYB		
ADJ/EN	1	1	I	Adjustable or enable input pin. Connect the external reference voltage to this pin. This pin connects to the error amplifier internally. A low signal below V_{IL} disables the device, and a high signal above V_{IH} enables the device. Connect the voltage reference directly or with a voltage divider for lower output voltages. To compensate for line influences, place a 0.1-µF capacitor close to this pin.
GND	2	2, 5	G	Ground pin.
IN	3	3	I	Input power-supply voltage pin. This pin is the device supply. For best transient response and to minimize input impedance, use the recommended value or larger ceramic capacitor from IN to GND as listed in the *Recommended Operating Conditions* table. Place the input capacitor as close to the input of the device as possible to compensate for line influences.
NC	5	—	—	NC pin. This pin is not internally connected. This pin can either be left floating or connected to GND for improved thermal performance.
OUT	4	4	O	Tracker output voltage pin. A capacitor is required from OUT to GND for stability. For best transient response, use the nominal recommended value or larger ceramic capacitor from OUT to GND; see the *Recommended Operating Conditions* table. Place the output capacitor as close to output of the device as possible.

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
V_{IN}	Unregulated input voltage	–40	45	V
V_{OUT}	Tracker output voltage	–5	45	V
$V_{ADJ/EN}$	Adjustable reference and enable input voltage	–0.3	45	V
V_{IN} - V_{OUT}	Input output voltage difference	–40	40	V
T_J	Operating junction temperature	–40	150	°C
T_{stg}	Storage temperature	–65	150	°C

(1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect the device reliability, functionality, performance, and shorten the device lifetime.

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6.2 ESD Ratings

				VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per AEC Q100-002[1]		±2000	V
		Charged-device model (CDM), per AEC Q100-011	All pins	±500	
			Corner pins	±750	

(1) AEC Q100-002 indicates that HBM stressing shall be in accordancewith the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	TYP	MAX	UNIT
V_{IN}	Unregulated input voltage	3		40	V
V_{OUT}	Regulated output voltage	2		40	V
V_{ADJ}	Adjust pin voltage	2		40	V
I_{OUT}	Output current	0		70	mA
C_{IN}	Input capacitor[1]	0	1		µF
C_{OUT}	Output capacitor[2]	1		200	µF
ESR	Output capacitor ESR requirements	0.001		3	Ω
T_J	Operating junction temperature	–40		150	°C

(1) For robust EMI performance the minimum input capacitance recommended is 500 nF.
(2) Effective output capacitance of 500 nF minimum required for stability.

6.4 Thermal Information

THERMAL METRIC[1] [2]		TPS7B4255-Q1		UNIT
		DBV (SOT-23)	DYB (SOT-23)	
		5 PINS	5 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	176.3	127.8	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	75.6	59.9	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	44.4	16.6	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	17.9	4.4	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	44.1	16.4	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	N/A	°C/W

(1) The thermal data is based on the JEDEC standard high K profile, JESD 51-7, two-signal, two-plane, four-layer board with 2-oz. copper. The copper pad is soldered to the thermal land pattern. Also, correct attachment procedure must be incorporated
(2) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application note.

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6.5 Electrical Characteristics

specified at T_J = –40°C to +150°C, V_{IN} = 13.5 V, I_{OUT} = 100 µA, C_{OUT} = 1 µF, 1 mΩ ≤ C_{OUT} ESR ≤ 3 Ω, C_{IN} = 1 µF, and V_{ADJ} = 5 V (unless otherwise noted); typical values are at T_J = 25°C

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
ΔV_{OUT}	Output voltage tracking accuracy	V_{IN} = V_{OUT} + 600 mV to 40 V, I_{OUT} = 100 µA to 70 mA	–5		5	mV
$\Delta V_{OUT(\Delta VIN)}$	Line regulation	V_{IN} = V_{OUT} + 600 mV to 40 V			0.5	mV
$\Delta V_{OUT(\Delta IOUT)}$	Load regulation	V_{IN} = V_{OUT} + 600 mV, I_{OUT} = 100 µA to 70 mA (1)			0.6	mV
I_Q	Quiescent current	V_{IN} = 5.6 V to 40 V, I_{OUT} = 100 µA, T_J = 25ºC		35	40	µA
		V_{IN} = 5.6 V to 40 V, I_{OUT} = 100 µA, -40ºC < T_J < 85ºC			45	
		V_{IN} = 5.6 V to 40 V, I_{OUT} = 100 µA			50	
I_{GND}	Ground current	V_{IN} = 5.6 V to 40 V, I_{OUT} = 70 mA, T_J = 25ºC			470	
		V_{IN} = 5.6 V to 40 V, I_{OUT} = 70 mA			550	
V_{DO}	Dropout voltage	I_{OUT} = 70 mA, V_{ADJ} ≥ 5 V, V_{IN} = V_{ADJ}			500	mV
		I_{OUT} = 50 mA, V_{ADJ} ≥ 5 V, V_{IN} = V_{ADJ}			365	
$I_{SHUTDOWN}$	Shutdown supply current (I_{GND})	$V_{ADJ/EN}$ = 0 V			3.25	µA
$I_{ADJ/EN}$	ADJ/EN pin current				0.3	
$V_{UVLO(RISING)}$	Rising input supply UVLO	V_{IN} rising	2.6	2.7	2.81	V
$V_{UVLO(FALLING)}$	Falling input supply UVLO	V_{IN} falling	2.3	2.4	2.5	
$V_{UVLO(HYST)}$	$V_{UVLO(IN)}$ hysteresis			300		mV
V_{IL}	Adjustable and enable logic input low level				0.85	V
V_{IH}	Adjustable and enable logic input high level		1.75			
I_{CL}	Output current limit	V_{IN} = V_{OUT} + 1 V, V_{OUT} short to 90% x V_{ADJ}	75	105	130	mA
PSRR	Power-supply ripple rejection	V_{IN} - V_{OUT} = 1 V, frequency = 100 Hz, I_{OUT} = 70 mA		80		dB
V_n	Output noise voltage	V_{OUT} = 3.3 V, I_{OUT} = 1 mA, BW = 10 Hz to 100 kHz, a 5 μV_{RMS} reference is used for this measurement		150		μV_{RMS}
I_{REV}	Reverse current at V_{IN}	V_{IN} = 0 V, V_{OUT} = 20 V, V_{ADJ} = 5 V	-0.25		0.25	µA
I_{REV-N1}	Reverse current at negative V_{IN}	V_{IN} = –20 V, V_{OUT} = 20 V, V_{ADJ} = 5 V	-0.5		0.5	
I_{REV-N2}	Reverse current at negative V_{IN}	V_{IN} = –20 V, V_{OUT} = 0 V, V_{ADJ} = 5 V	-0.5		0.5	
T_J	Junction temperature		–40		150	°C
$T_{SD(SHUTDOWN)}$	Junction shutdown temperature			175		°C
$T_{SD(HYST)}$	Hysteresis of thermal shutdown			15		°C

(1) Power dissipation is limited to 2 W for device production testing purposes. The power dissipation can be higher during normal operation. Please see the thermal dissipation section for more information on how much power the device can dissipate while maintaining a junction temperature below 150°C.

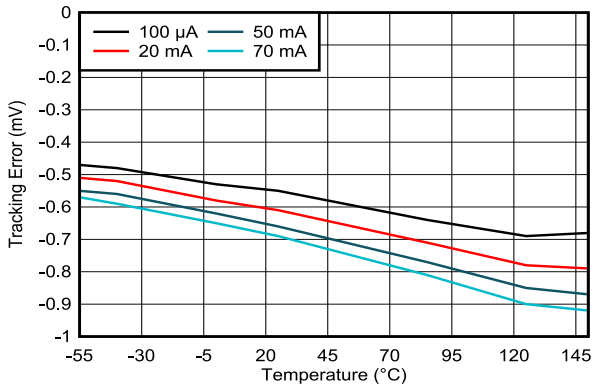
6.6 Timing Characteristics

specified at V_{IN} = 13.5 V, I_{OUT} = 100 µA, C_{OUT} = 1 µF, C_{IN} = 1 µF, and V_{ADJ} = 5 V (unless otherwise noted), and V_{ADJ} = 5 V (unless otherwise noted); typical values are at T_J = 25°C

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Timing Characteristics						
$t_{startup}$	Start-up time	Time from EN high to V_{OUT} = 95% × V_{ADJ}		255		µs

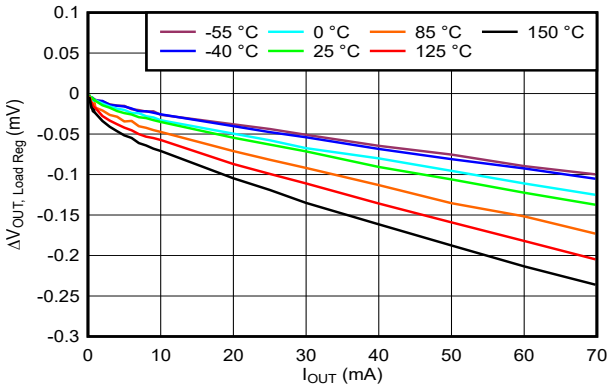
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6.7 Typical Characteristics



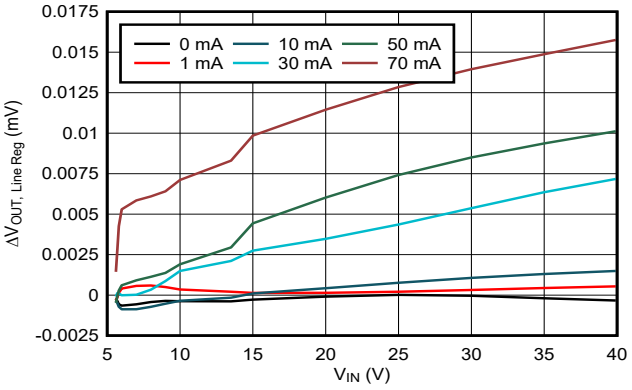
V_{IN} = 13.5 V, V_{ADJ} = 5 V

Figure 6-1. Tracking Error vs Ambient Temperature



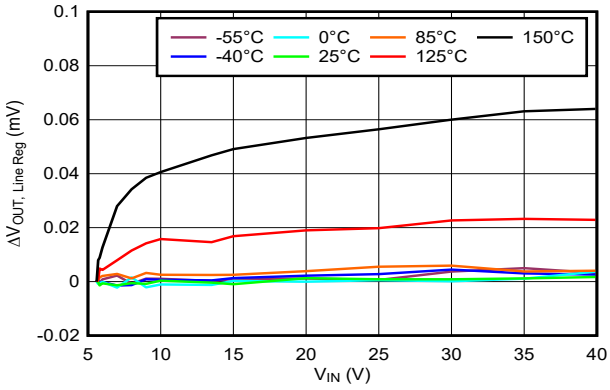
V_{IN} = 13.5 V, V_{ADJ} = 5 V

Figure 6-2. Load Regulation



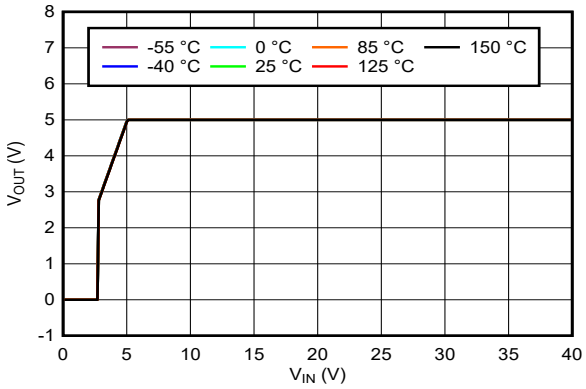
V_{ADJ} = 5 V, T_{AMB} = 25°C

Figure 6-3. Line Regulation



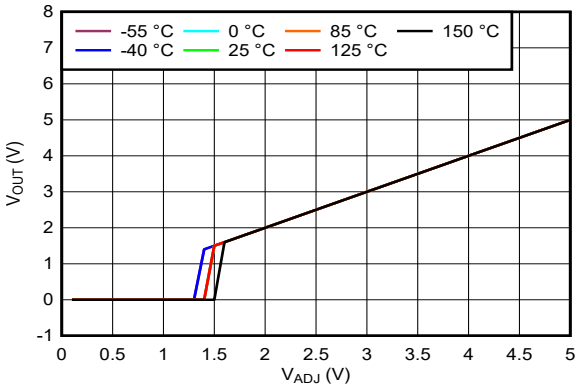
V_{ADJ} = 5 V, I_{OUT} = 10 mA

Figure 6-4. Line Regulation



V_{ADJ} = 5 V, I_{OUT} = 10 mA

Figure 6-5. Output Voltage vs Input Voltage

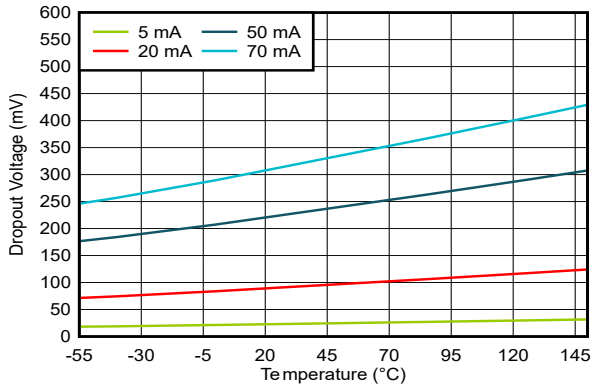


V_{IN} = 13.5 V, I_{OUT} = 10 mA

Figure 6-6. Output Voltage vs Adjustable Reference Voltage

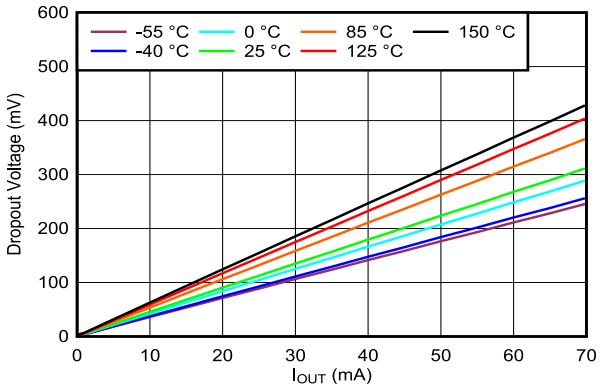
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6.7 Typical Characteristics (continued)



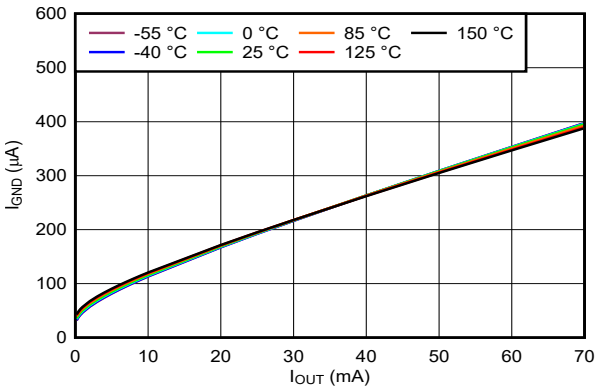
V_{IN} = 5 V, V_{ADJ} = 5 V

Figure 6-7. Dropout Voltage vs Ambient Temperature



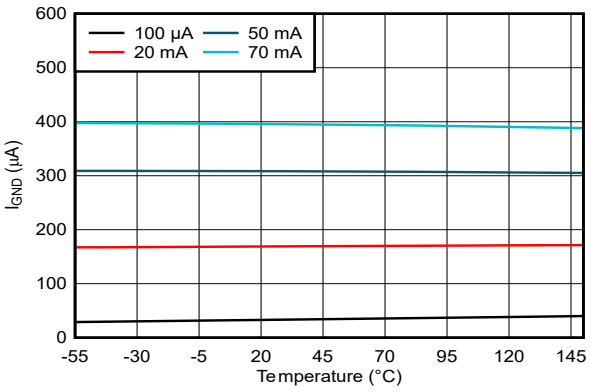
V_{IN} = 5 V, V_{ADJ} = 5 V

Figure 6-8. Dropout Voltage vs Output Current



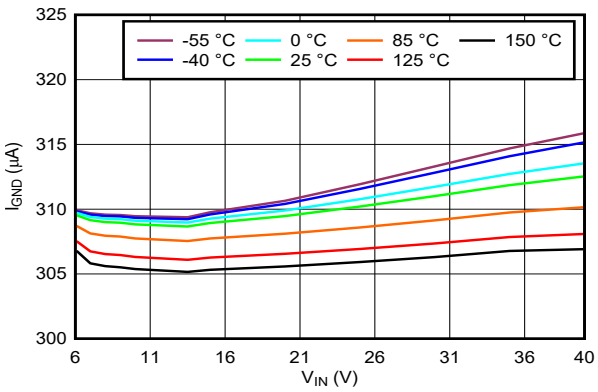
V_{IN} = 13.5 V, V_{ADJ} = 5 V

Figure 6-9. Ground Current vs Output Current



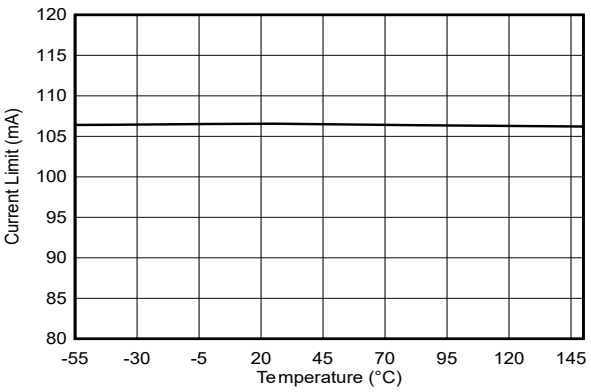
V_{IN} = 13.5 V, V_{ADJ} = 5 V

Figure 6-10. Ground Current vs Ambient Temperature



V_{ADJ} = 5 V, I_{OUT} = 50 mA

Figure 6-11. Ground Current vs Input Voltage

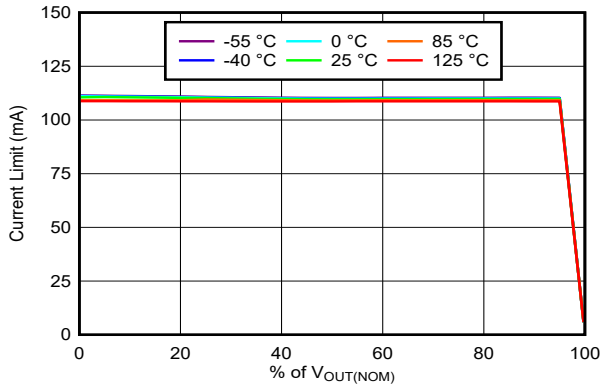


V_{IN} = 13.5 V, V_{ADJ} = 5 V

Figure 6-12. Current Limit vs Ambient Temperature

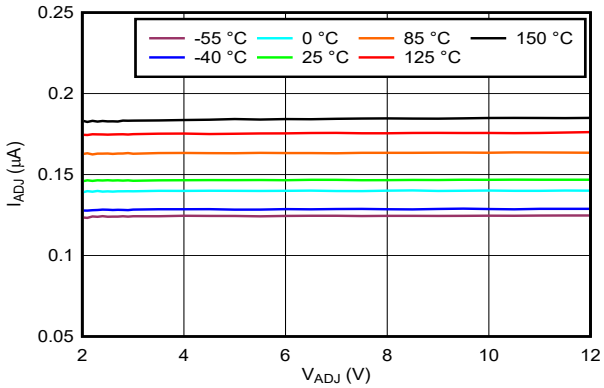
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6.7 Typical Characteristics (continued)



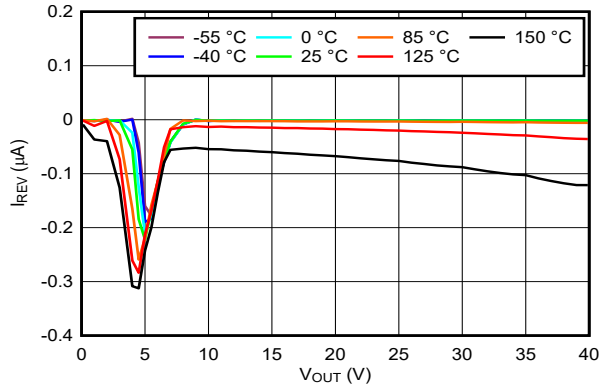
V_{IN} = 13.5 V, V_{ADJ} = 5 V

Figure 6-13. Current Limit Profile vs. Output Voltage



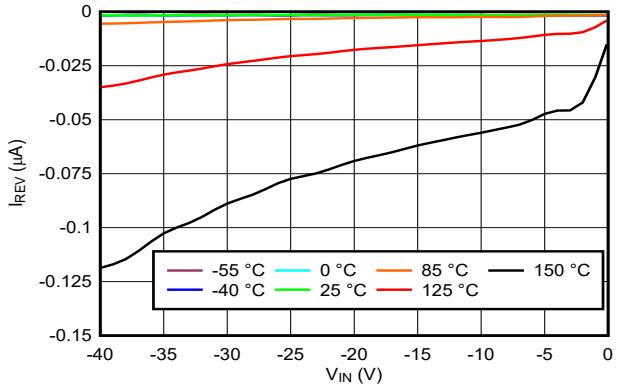
V_{IN} = 13.5 V, I_{OUT} = 0 mA

Figure 6-14. Adjustable Pin Current vs Adjustable Pin Voltage



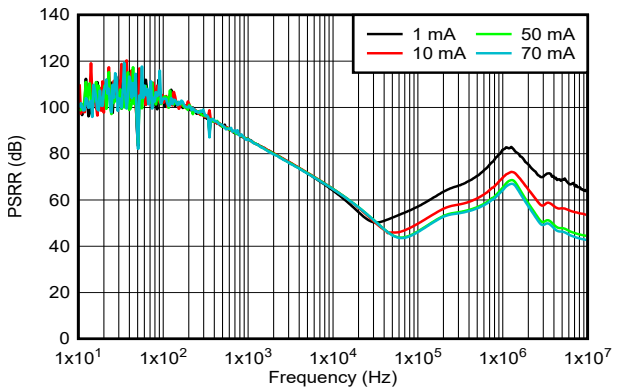
V_{IN} = 0 V, V_{ADJ} = 5 V

Figure 6-15. Reverse Current vs Output Voltage



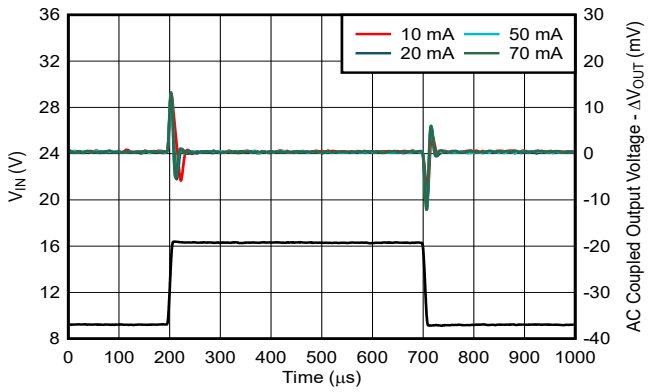
V_{OUT} = 0 V, V_{ADJ} = 5 V

Figure 6-16. Reverse Current vs Input Voltage



V_{IN} = 13.5 V, V_{ADJ} = 5 V, C_{OUT} = 10 µF, T_{AMB} = 25°C

Figure 6-17. Power-Supply Rejection Ratio vs Frequency

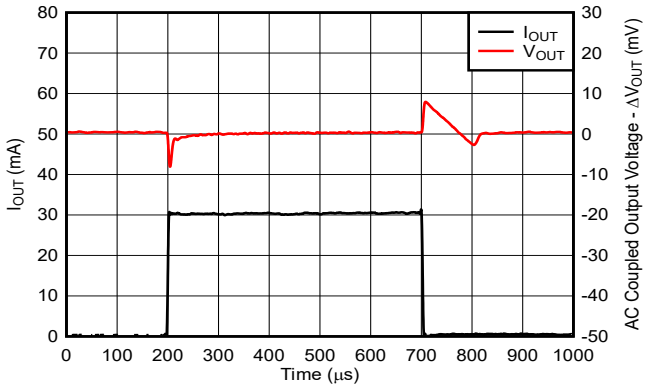


V_{ADJ} = 5 V, C_{OUT} = 10 µF, V_{IN} = 9 V to 16 V,
V_{IN} ramp rate = 1 V/µs

Figure 6-18. Line Transient

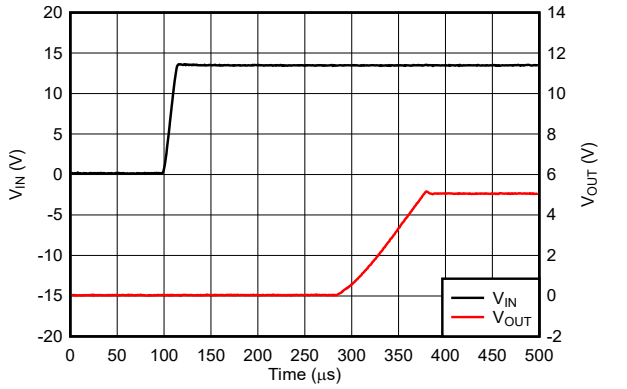
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6.7 Typical Characteristics (continued)



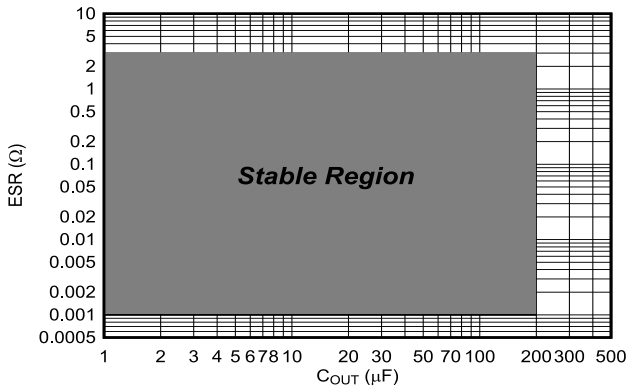
V_{IN} = 13.5 V, V_{ADJ} = 5 V, C_{OUT} = 10 µF, I_{OUT} = 1 mA to 30 mA, I_{OUT} ramp rate = 1 A/µs

Figure 6-19. Load Transient



V_{IN} = 13.5 V, V_{ADJ} = 5 V, V_{IN} rate of rise = 1 V/µs, C_{OUT} = 1 µF

Figure 6-20. Start-Up Profile



1 mΩ ≤ ESR ≤ 3 Ω, 1 µF ≤ C_{OUT} ≤ 200 µF

Figure 6-21. ESR vs Load Capacitance

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7 Detailed Description

7.1 Overview

The TPS7B4255-Q1 is an integrated, low-dropout (LDO) voltage tracker with ultra-low tracking tolerance. Because of the high risk of cable shorts when powering sensors off-board, multiple protection features are built into the LDO including short to battery, short to GND, and reverse current protection.

This device features thermal shutdown protection, brick-wall current limiting, undervoltage lockout (UVLO), reverse current, and reverse polarity protection.

7.2 Functional Block Diagram

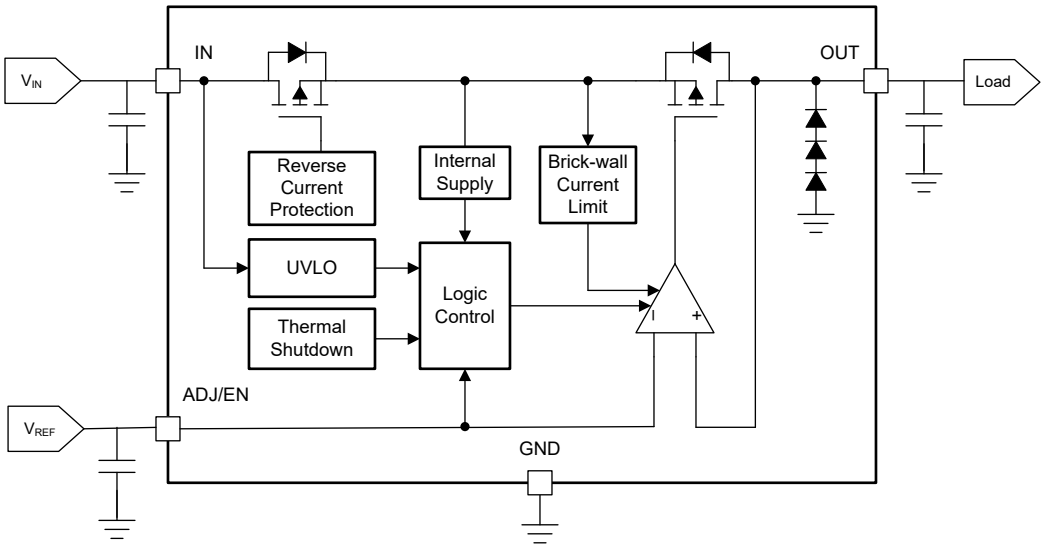


Figure 7-1. Functional Block Diagram

7.3 Feature Description

7.3.1 Tracker Output Voltage (V_{OUT})

This device is a tracking LDO; thus, with sufficient V_{IN} (≥3 V) applied, the output voltage is determined by the voltage provided to the ADJ/EN pin. The LDO remains disabled as long as $V_{ADJ/EN}$ is less than V_{IL}. When $V_{ADJ/EN}$ exceeds V_{IH}, the output begins to rise to the voltage on the ADJ/EN pin. The output rises linearly as determined by the load, the output capacitor, and the current limit. When the voltage reaches the level on the ADJ/EN pin, the output voltage remains within 5 mV from the voltage set on the ADJ/EN pin over all specified operating conditions.

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7.3.1.1 Output Voltage Equal to the Reference Voltage

As shown in Figure 7-2, connect the external reference voltage directly to the ADJ/EN pin. When connected properly, and as given in Equation 1, the LDO output voltage is equal to the reference voltage.

$$V_{OUT} = V_{REF} \quad (1)$$

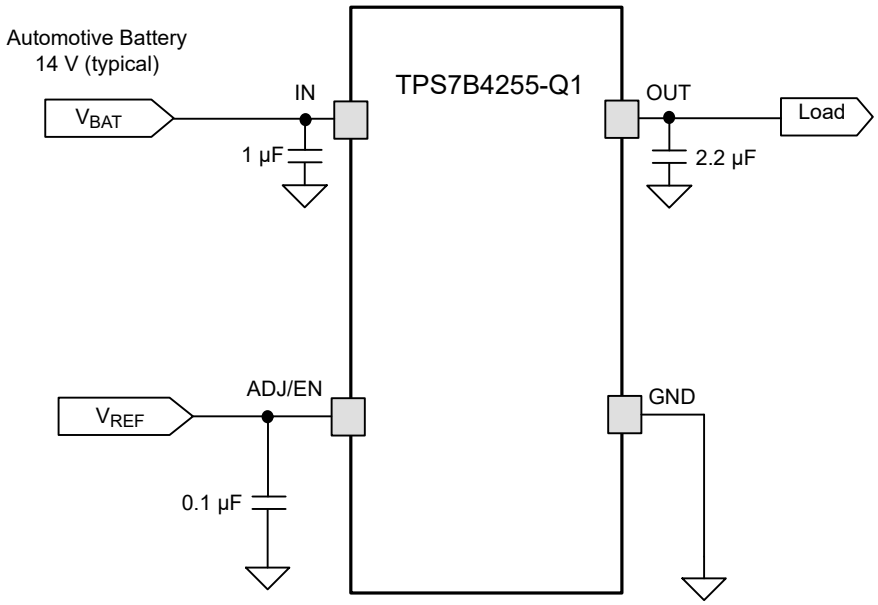


Figure 7-2. Tracker Output Voltage Equal to the Reference Voltage

7.3.1.2 Output Voltage Less Than the Reference Voltage

Connecting an external resistor divider at the ADJ/EN pin, as shown in Figure 7-3, can help generate an output voltage that is lower than the reference voltage. Both the R_1 and R_2 resistors must be less than 100 kΩ in value. Equation 2 calculates V_{OUT}.

$$V_{OUT} = \frac{V_{REF} * R_2}{R_1 + R_2} \quad (2)$$

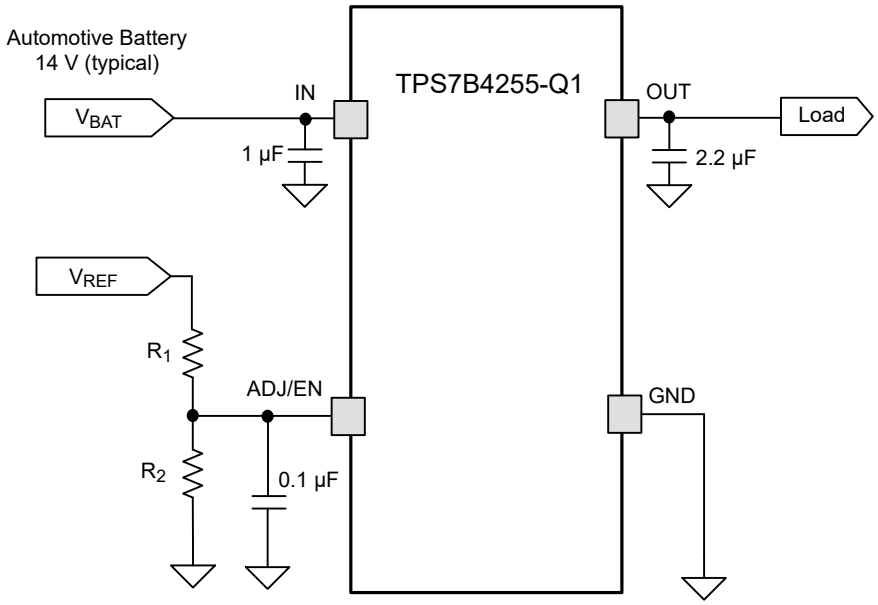


Figure 7-3. Tracker Output Voltage Lower Than the Reference Voltage

7.3.2 Reverse Current Protection

The TPS7B4255-Q1 incorporates a back-to-back PMOS topology that protects the device from damage against a fault condition, resulting in V_{OUT} being higher than V_{IN} and the subsequent flow of reverse current. No damage occurs to the device if this fault condition occurs, provided the *Absolute Maximum Ratings* are not violated. This integrated protection feature eliminates the need for an external diode. The reverse current comparator typically responds to a reverse voltage condition in 1 µs, and along with the body diode of the blocking PMOS transistor, limits the reverse current to I_{REV}.

7.3.3 Undervoltage Lockout

The device has an internally fixed undervoltage lockout threshold. Undervoltage lockout activates when the input voltage V_{IN} drops below the undervoltage lockout (UVLO) level; see the $V_{UVLO(FALLING)}$ parameter in the *Electrical Characteristics* table. This activation makes sure the regulator is not latched into an unknown state during a low input supply voltage. If the input voltage has a negative transient that drops below the UVLO threshold and recovers, the regulator shuts down and powers up in the standard power-up sequence when the input voltage recovers to the required level (see the $V_{UVLO(RISING)}$ parameter in the *Electrical Characteristics* table).

7.3.4 Thermal Protection

Thermal protection disables the output when the junction temperature rises to approximately 175°C, which allows the device to cool. When the junction temperature cools to approximately 160°C, the output circuitry enables. Based on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit can cycle off and on until the excessive power dissipation condition is removed. This cycling limits the dissipation of the regulator, thus protecting the regulator from damage as a result of overheating.

The internal protection circuitry of the TPS7B4255-Q1 is designed to protect against overload conditions. The circuitry is not intended to replace proper heat sinking. Continuously running the TPS7B4255-Q1 into thermal shutdown degrades device reliability.

7.3.5 Current Limit

The device has an internal current limit circuit to protect the device during overcurrent or shorting conditions. The current limit circuit, as shown in Figure 7-4, is a brick-wall scheme. When the device is in current limit, the device sources I_{CL} and the output voltage is not regulated. In this scenario, the output voltage depends on the load impedance.

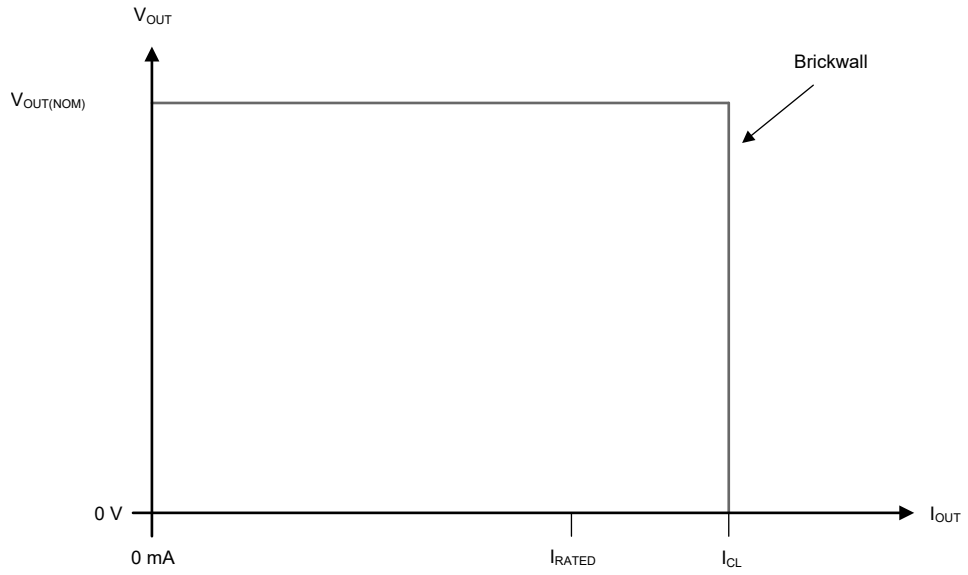


Figure 7-4. Current Limit: Brick-Wall Scheme

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During a current limit event, the potential for high power dissipation exists because of the elevated current level and the increased input-to-output differential voltage (V_{IN} – V_{OUT}). If the device heats enough, the device can enter thermal shutdown. If the current-limit condition is not removed when the device turns back on after cooling, the device can enter thermal shutdown again and continue this cycle until the current limit condition is removed. The device survives this fault, but repeatedly operating in this mode degrades long-term reliability.

7.3.6 Output Short to Battery

When the output is shorted to the supply (as shown in Figure 7-5), the TPS7B4255-Q1 survives and no damage occurs to the device. As shown in Figure 7-6, a short to the supply can also occur when the device is powered by an isolated supply at a lower voltage. In this example, the TPS7B4255-Q1 supply input voltage is set at 7 V when a short to the main supply (14 V typical) occurs on V_{OUT}, which typically runs at 5 V. The device survives without damage, and the back-to-back PMOS topology helps limit the continuous reverse current that flows out through V_{IN} to less than 0.25 µA.

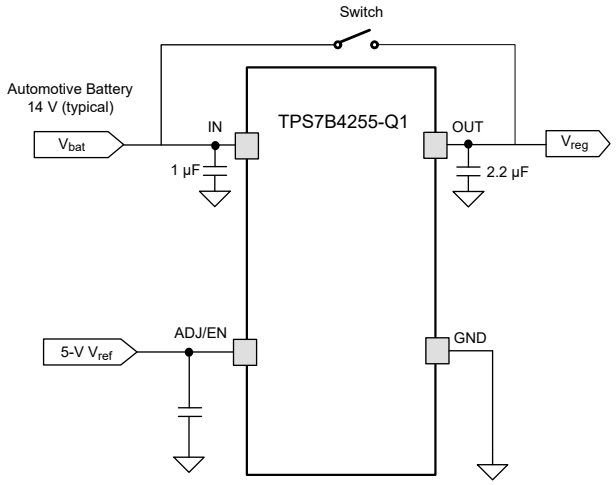


Figure 7-5. Output Voltage Short to Battery

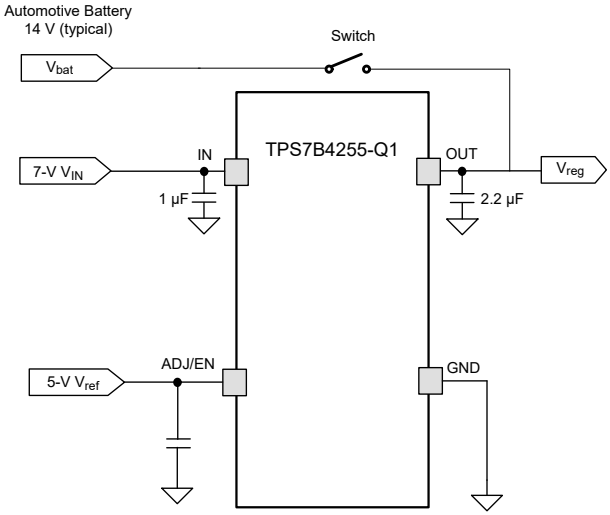


Figure 7-6. Output Voltage Higher Than the Input

7.3.7 Tracking Regulator With an Enable Circuit

Pulling the reference voltage below V_{IL} disables the device, and the device enters a sleep state where the device draws 3.25 µA (maximum) from the power supply. In a typical application, the reference voltage is generally sourced from another LDO voltage rail. A scenario where the device must be disabled without a shutdown of the reference voltage can occur; the device can be configured as shown in Figure 7-7 in this case. The TPS7B84-Q1 is a 150-mA LDO with ultra-low quiescent current that provides the reference voltage to both the TPS7B4255-Q1 and the ADC. The operational status of the device is controlled by a microcontroller (MCU) input or output (I/O).

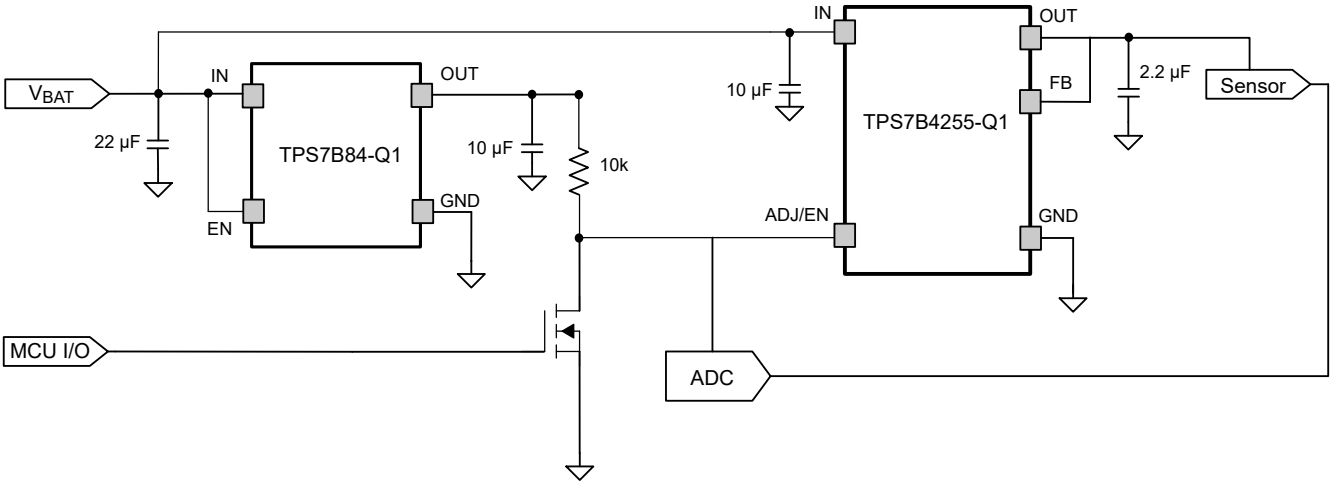


Figure 7-7. Tracking an LDO With an Enable Circuit

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7.4 Device Functional Modes

Table 7-1 shows the conditions that lead to the different modes of operation. See the *Electrical Characteristics* table for parameter values.

Table 7-1. Device Functional Mode Comparison

OPERATING MODE	PARAMETER			
	V_{IN}	$V_{ADJ/EN}$	I_{OUT}	T_J
Normal operation	$V_{IN} > V_{OUT(Nom)} + V_{DO}$ and $V_{IN} \geq V_{IN(min)}$	$V_{ADJ/EN} > V_{IH}$	$I_{OUT} \leq I_{OUT(max)}$	$T_J < T_{SD(shutdown)}$
Dropout operation	$V_{IN(min)} < V_{IN} < V_{OUT(nom)} + V_{DO}$	$V_{ADJ/EN} > V_{IH}$	$I_{OUT} \leq I_{OUT(max)}$	$T_J < T_{SD(shutdown)}$
Disabled (any true condition disables the device)	$V_{IN} < V_{UVLO}$	$V_{ADJ/EN} < V_{IL}$	Not applicable	$T_J > T_{SD(shutdown)}$

The device turns on when V_{IN} is greater than $V_{UVLO(RISING)}$ and $V_{ADJ/EN}$ is greater than the enable rising threshold V_{IH}.

7.4.1 Normal Operation

The device output voltage $V_{OUT(Nom)}$ tracks the reference voltage $V_{ADJ/EN}$ when the following conditions are met:

- The input voltage is at least 3 V ($V_{IN(min)}$) and greater than the nominal output voltage plus the dropout voltage ($V_{OUT(nom)} + V_{DO}$)
- The reference voltage at the ADJ/EN pin is greater than the enable rising threshold V_{IH} and stays stable at $V_{OUT(Nom)}$
- The output current is less than $I_{OUT(max)}$ ($I_{OUT} \leq 70$ mA)
- The device junction temperature is less than the thermal shutdown temperature ($T_J < T_{SD}$)

7.4.2 Dropout Operation

If the input voltage is lower than the nominal output voltage plus the specified dropout voltage, but all other conditions are met for normal operation, the device operates in dropout mode. In this mode, the output voltage tracks the input voltage. During this mode, the transient performance of the device becomes significantly degraded because the pass transistor is in the ohmic or triode region, and acts as a switch. Line or load transients in dropout can result in large output-voltage deviations.

When the device is in a steady dropout state (defined as when the device is in dropout, $V_{IN} < V_{OUT(NOM)} + V_{DO}$, directly after being in a normal regulation state, but *not* during start up), the pass transistor is driven into the ohmic or triode region. When the input voltage returns to a value greater than or equal to the nominal output voltage plus the dropout voltage ($V_{OUT(NOM)} + V_{DO}$), the output voltage can overshoot for a short period of time while the device pulls the pass transistor back into the saturation region.

7.4.3 Operation With V_{IN} < 3 V

For input voltages below 3 V and above $V_{UVLO(FALLING)}$, the LDO continues to operate but certain circuits can possibly not have the proper headroom to operate within specification. When the input voltage drops below $V_{UVLO(FALLING)}$ the device shuts off.

7.4.4 Disable With ADJ/EN Control

The ADJ/EN pin operates as both the reference and the enable pin to the LDO. The output of the device can be shutdown by forcing $V_{ADJ/EN}$ less than V_{IL}. When disabled, the pass transistor is turned off, the internal circuits are shutdown, and the LDO is in a low-power mode.

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8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

8.1.1 Dropout Voltage

Dropout voltage (V_{DO}) is defined as the input voltage minus the output voltage ($V_{IN} – V_{OUT}$) when the pass transistor is fully on. This condition arises when the input voltage falls to the point where the error amplifier must drive the gate of the pass transistor to the rail and has no remaining headroom for the control loop to operate. The pass transistor is in the ohmic or triode region of operation, and acts as a switch. The dropout voltage directly specifies a minimum input voltage greater than the nominal programmed output voltage at which the output voltage is expected to stay in regulation. If the input voltage falls to less than the nominal output regulation, then the output voltage follows, minus the dropout voltage (V_{DO}).

In dropout mode, the output is no longer regulated, and transient performance is severely degraded. The device loses PSRR, and load transients can cause large output voltage deviation.

For a CMOS regulator, the dropout voltage is determined by the drain-source on-state resistance ($R_{DS(ON)}$) of the pass transistor. Therefore, if the linear regulator operates at less than the rated output current (I_{RATED}, see the *Recommended Operating Conditions* table), the dropout voltage for that current scales accordingly. The following equation calculates the $R_{DS(ON)}$ of the device.

$$R_{DS(ON)} = \frac{V_{DO}}{I_{RATED}} \tag{3}$$

8.1.2 Reverse Current

The TPS7B4255-Q1 incorporates reverse current protection that prevents damage from a fault condition, resulting in V_{OUT} being higher than V_{IN}. During such a fault condition, where the V_{IN} and V_{OUT} absolute maximum ratings are not violated and $V_{OUT} – V_{IN}$ is less than 40 V, no damage occurs and less than 0.5 µA of reverse current flows through the LDO. The reverse current comparator typically responds to a reverse voltage condition and, along with the body diode of the blocking PMOS transistor, limits the reverse current in 1 µs.

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8.2 Typical Application

Figure 8-1 shows a typical application circuit for the TPS7B4255-Q1.

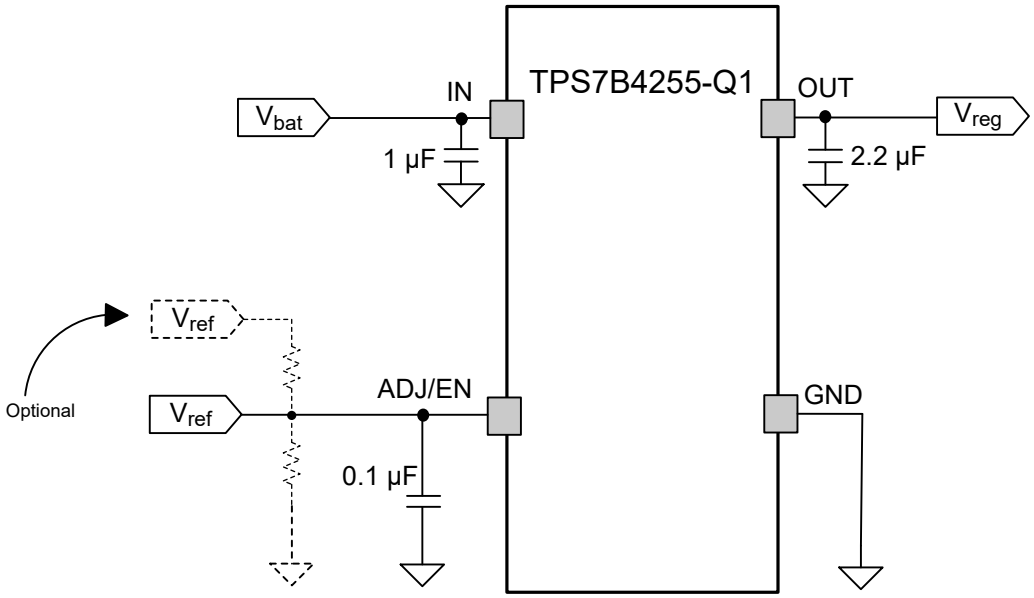


Figure 8-1. Typical Application Schematic

8.2.1 Design Requirements

Use the parameters listed in Table 8-1 for this design example.

Table 8-1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUES
Input voltage	3 V to 40 V
ADJ/EN reference voltage	2 V to 40 V
Output voltage	2 V to 40 V
Output current rating	70 mA
Output capacitor range	1 µF to 200 µF
Output capacitor ESR range	1 mΩ to 3 Ω

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8.2.2 Detailed Design Procedure

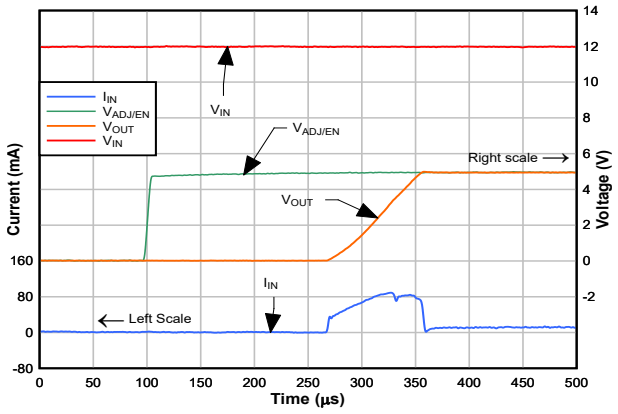
8.2.2.1 Input and Output Capacitor Selection

Depending on the end application, different values of external components can be used. An application can require a larger output capacitor during fast load steps to prevent a reset from occurring. Use a low ESR ceramic capacitor with a dielectric of type X5R or X7R for better load transient response.

The TPS7B4255-Q1 requires an output capacitor of at least 1 µF (500 nF or larger capacitance) for stability and an equivalent series resistance (ESR) between 0.001 Ω and 3 Ω. Without the output capacitor, the regulator oscillates. For best transient performance, use X5R- and X7R-type ceramic capacitors because these capacitors have minimal variation in value and ESR over temperature. When choosing a capacitor for a specific application, be mindful of the DC bias characteristics for the capacitor. Higher output voltages cause a significant derating of the capacitor. For best performance, the maximum recommended output capacitor is 200 µF.

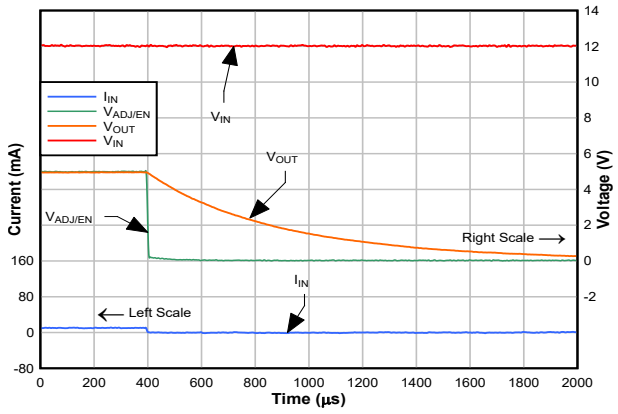
Although an input capacitor is not required for stability, good analog design practice is to connect a capacitor from IN to GND, connected close to the device pins. Some input supplies have a high impedance; thus, placing the input capacitor on the input supply helps reduce the input impedance. This capacitor counteracts reactive input sources and improves transient response, input ripple, and PSRR. If the input supply has a high impedance over a large range of frequencies, several input capacitors can be used in parallel to lower the impedance over frequency. Use a higher-value capacitor if large, fast rise-time load transients are anticipated, or if the device is located several inches from the input power source.

8.2.3 Application Curves



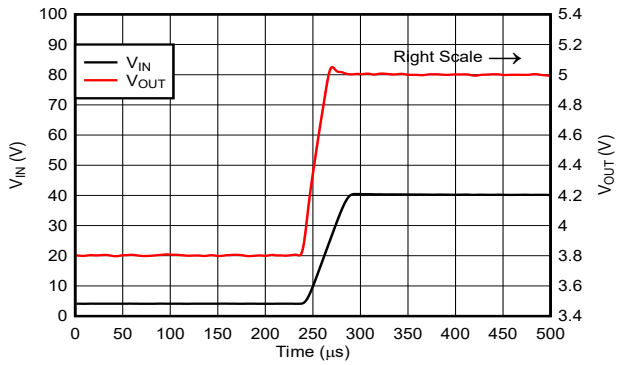
V_{IN} = 12 V, $V_{ADJ/EN}$ = 5 V, $V_{ADJ/EN}$ slew rate = 1 V/µs, C_{IN} = C_{OUT} = 1 µF, R_{LOAD} = 470 Ω

Figure 8-2. Power-Up



V_{IN} = 12 V, $V_{ADJ/EN}$ = 5 V, $V_{ADJ/EN}$ slew rate = 1 V/µs, C_{IN} = C_{OUT} = 1 µF, R_{LOAD} = 470 Ω

Figure 8-3. Power-Down



C_{OUT} = 1 µF, $V_{ADJ/EN}$ = 5 V, I_{OUT} = 70 mA, V_{IN} slew rate = 1 V/µs

Figure 8-4. Dropout Exit Recovery

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8.3 Power Supply Recommendations

The device is designed to operate from an input voltage supply range from 3 V to 40 V.

8.4 Layout

8.4.1 Layout Guidelines

For best overall performance, place all circuit components on the same side of the circuit board and as near as practical to the respective LDO pin connections. Place ground return connections to the input and output capacitor, and to the LDO ground pin as close as possible to each other, connected by a wide, component-side, copper surface. Using vias and long traces to the input and output capacitors is strongly discouraged and negatively affects system performance. Use a ground reference plane either embedded in the PCB or located on the bottom side of the PCB opposite the components. This reference plane serves to provide accuracy of the output voltage, shield noise, and behaves similarly to a thermal plane to spread (or sink) heat from the LDO device when connected to the thermal pad. In most applications, this ground plane is necessary to meet thermal requirements.

8.4.1.1 Package Mounting

Solder-pad footprint recommendations for the TPS7B4255-Q1 are available at the end of this document and at www.ti.com.

TI's DYB package footprint can be used for both the DYB package as well as the DBV package for easy multisourcing.

8.4.1.2 Board Layout Recommendations to Improve PSRR and Noise Performance

To improve AC performance (such as PSRR, output noise, and transient response), design the board with separate ground planes for V_{IN} and V_{OUT}, with each ground plane connected only at the GND pin of the device. In addition, the ground connection for the output capacitor must connect directly to the GND pin of the device.

Equivalent series inductance (ESL) and ESR must be minimized in order to maximize performance and ensure stability. Every capacitor must be placed as close as possible to the device and on the same side of the printed circuit board (PCB) as the regulator.

Do not place any of the capacitors on the opposite side of the PCB from where the regulator is installed. Using vias and long traces is strongly discouraged because of the negative impact on system performance. Vias and long traces can also cause instability.

If possible, and to make sure that the maximum performance is as denoted in this product data sheet, use the same layout pattern used for the TPS7B4255-Q1 evaluation board, available at www.ti.com.

8.4.1.3 Power Dissipation and Thermal Considerations

Equation 4 calculates the device power dissipation.

$$P_D = I_{OUT} \times (V_{IN} - V_{OUT}) + I_Q \times V_{IN} \quad (4)$$

where:

- P_D = Continuous power dissipation
- I_{OUT} = Output current
- V_{IN} = Input voltage
- V_{OUT} = Output voltage
- I_Q = Quiescent current

Because I_Q is much less than I_{OUT}, the term $I_Q \times V_{IN}$ in Equation 4 can be ignored.

Calculate the junction temperature (T_J) with Equation 5 for a device under operation at a given ambient air temperature (T_A).

$$T_J = T_A + (R_{\theta JA} \times P_D) \quad (5)$$

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where:

- $R_{\theta JA}$ = Junction-to-junction-ambient air thermal impedance

Equation 6 calculates a rise in junction temperature because of power dissipation.

$$\Delta T = T_J - T_A = (R_{\theta JA} \times P_D) \quad (6)$$

The maximum ambient air temperature (T_{AMAX}) at which the device can operate can be calculated with Equation 7 for a given maximum junction temperature (T_{JMAX}).

$$T_{AMAX} = T_{JMAX} - (R_{\theta JA} \times P_D) \quad (7)$$

8.4.1.4 Thermal Performance Versus Copper Area

The most used thermal resistance parameter $R_{\theta JA}$ is highly dependent on the heat-spreading capability built into the particular PCB design, and therefore varies according to the total copper area, copper weight, and location of the planes. The $R_{\theta JA}$ recorded in the *Thermal Information* table is determined by the JEDEC standard (Figure 8-5), PCB, and copper-spreading area, and is only used as a relative measure of package thermal performance. For a well-designed thermal layout, $R_{\theta JA}$ is actually the sum of the package junction-to-case (bottom) thermal resistance ($R_{\theta JCbot}$) plus the thermal resistance contribution by the PCB copper.

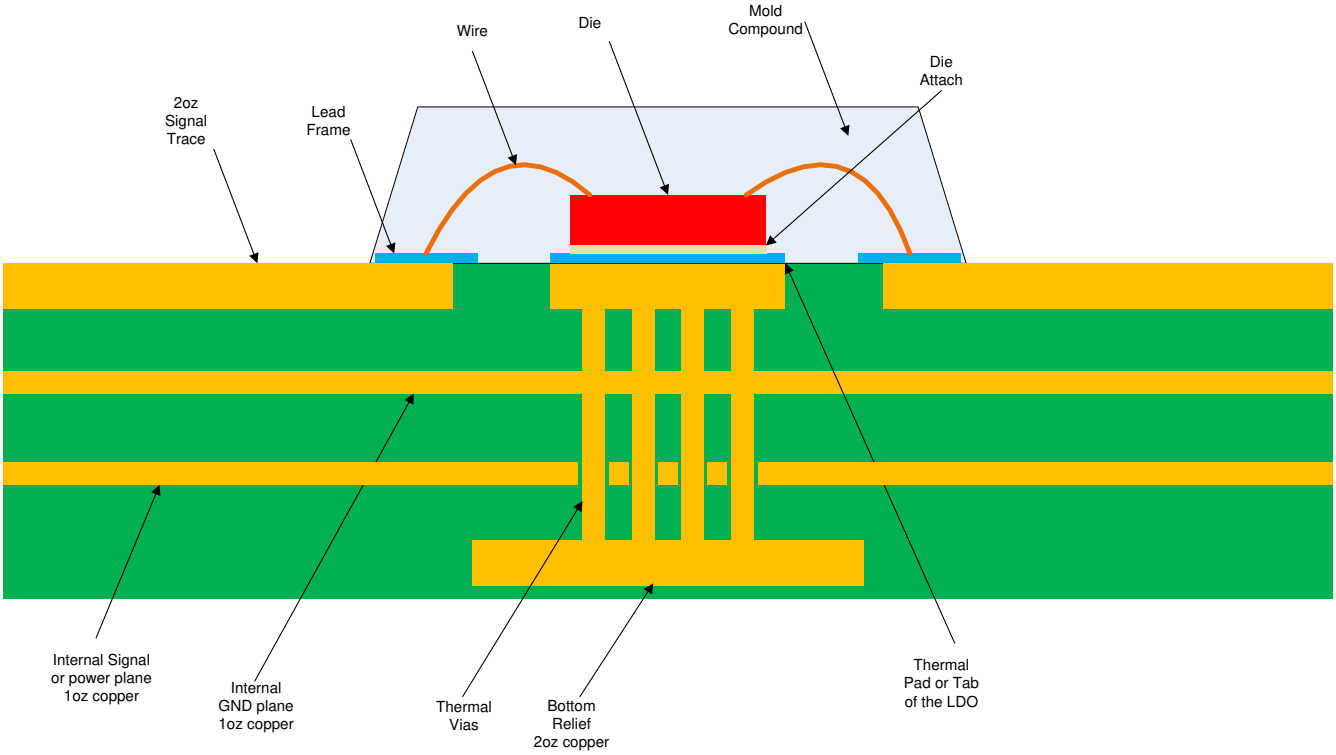


Figure 8-5. JEDEC Standard 2s2p PCB

Figure 8-6 through Figure 8-9 illustrate the functions of $R_{\theta JA}$ and ψ_{JB} versus copper area and thickness for the DBV package and DYB package. These plots are generated with a 101.6-mm × 101.6-mm × 1.6-mm PCB of two and four layers. For the 4-layer board, inner planes use 1-oz copper thickness. Outer layers are simulated with both 1-oz and 2-oz copper thickness. A 4 × 5 (DBV and DYB package) array of thermal vias with a 300-µm drill diameter and 25-µm copper plating is located as close as practical to the GND pin of the device. The thermal vias connect the top layer, the bottom layer and, in the case of the 4-layer board, the first inner GND plane. Each of the layers has a copper plane of equal area. The *PowerPAD™ Thermally Enhanced Package* application note discusses the impact that thermal vias have on thermal performance.

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As shown in Figure 8-7, ψ_{JB} increases with additional connecting copper area. The reason for this increase is that the board temperature is measured at the copper near the GND pin, and because the GND pin is fused to the die pad, more heat escapes through the GND pin when more copper is connected to the pad, and thus the temperature at this point is higher. Consequently the ψ_{JB} increases. This increase does not imply that heat sinking for the device is reduced when more connecting copper is added. Increasing connecting copper area always increases board-level heat sinking for the device. Furthermore, the boards used for Figure 8-7 have vias connecting to internal copper planes. Therefore, ψ_{JB} is much higher than what is specified in the *Thermal Information* table, which uses the high-K board layout specified in JESD51-7 that has no thermal vias.

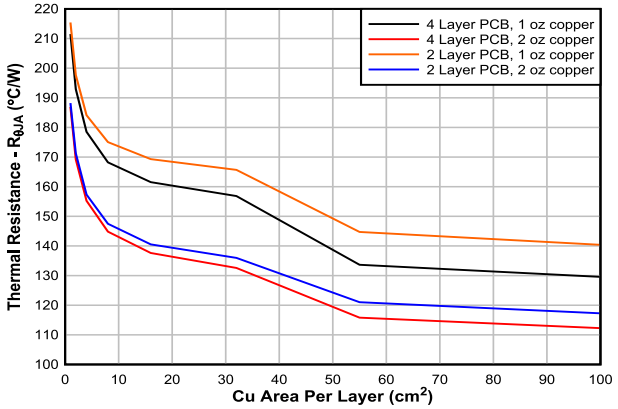


Figure 8-6. $R_{\theta JA}$ vs Copper Area (DBV Package)

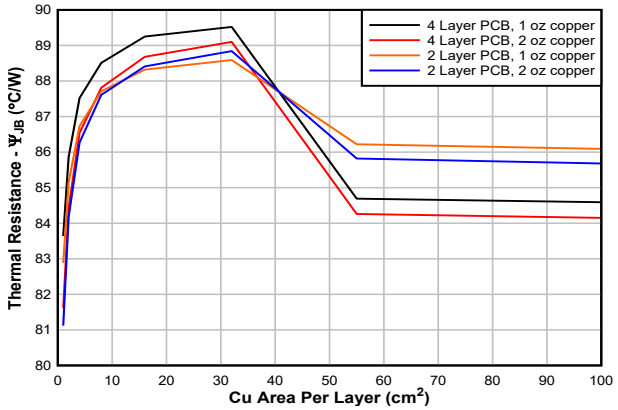


Figure 8-7. ψ_{JB} vs Copper Area (DBV Package)

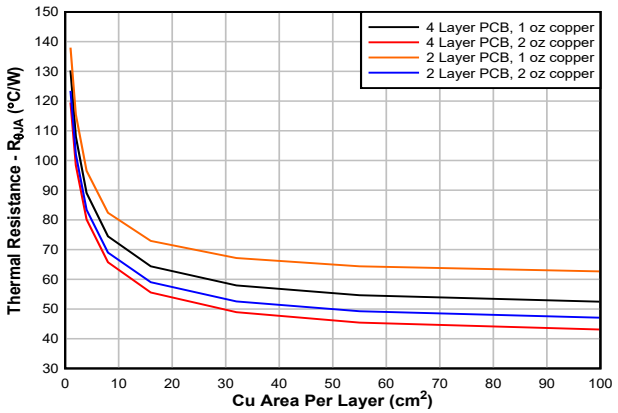


Figure 8-8. $R_{\theta JA}$ vs Copper Area (DYB Package)

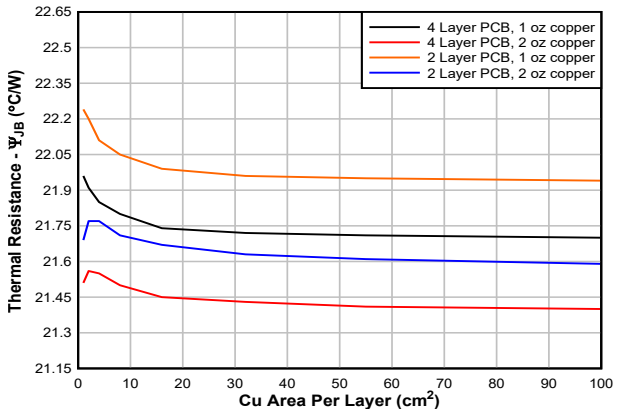


Figure 8-9. ψ_{JB} vs Copper Area (DYB Package)

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8.4.2 Layout Examples

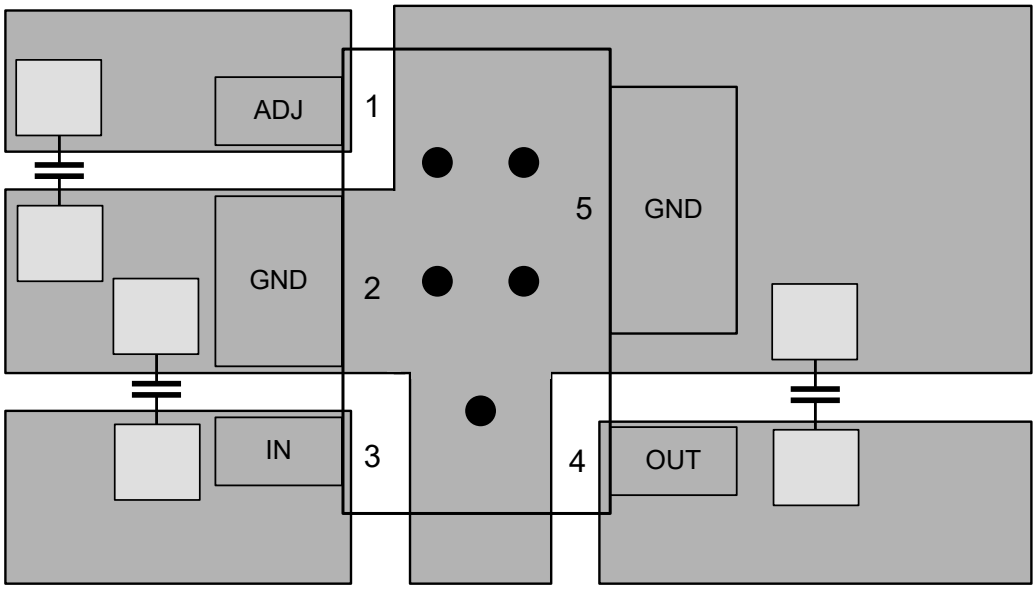


Figure 8-10. DYB Package Layout Example

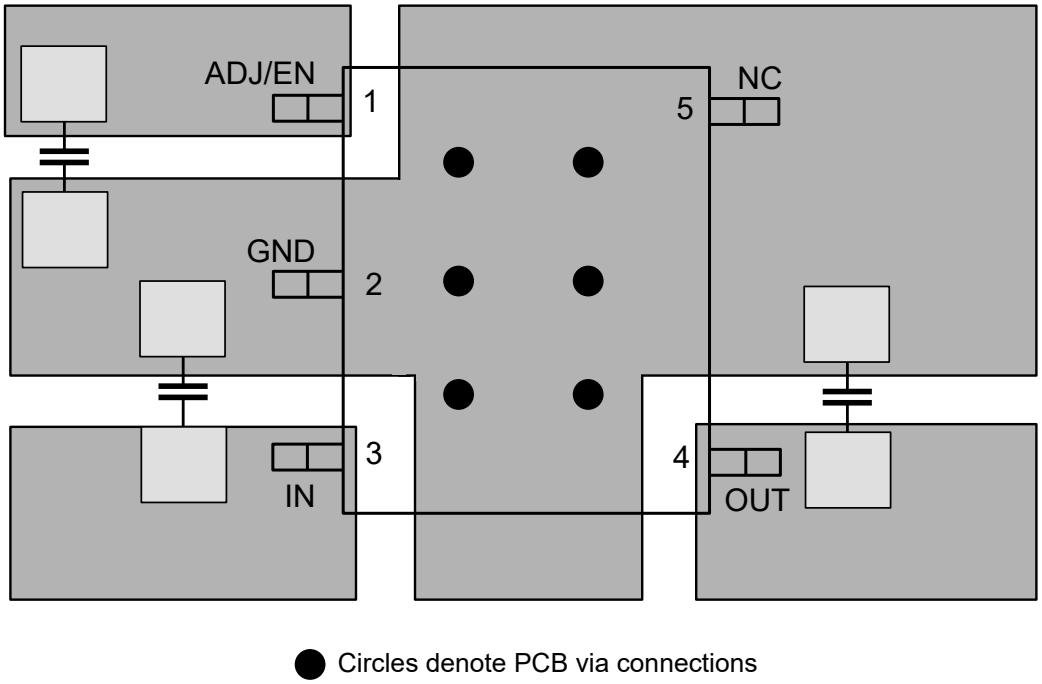


Figure 8-11. DBV Package Layout Example

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9 Device and Documentation Support

9.1 Device Support

9.1.1 Device Nomenclature

Table 9-1. Device Nomenclature (1)

PRODUCT	V_{OUT}
TPS7B4255**Q yyyR Q1**	**Q** indicates that this device is a grade-1 device in accordance with the AEC-Q100 standard. **yyy** is the package designator. **R** is the packaging quantity. **Q1** indicates that this device is an automotive grade (AEC-Q100) device.

(1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or visit the device product folder on www.ti.com.

9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.3 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.6 Glossary

TI Glossary — This glossary lists and explains terms, acronyms, and definitions.

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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10.1 Mechanical Data

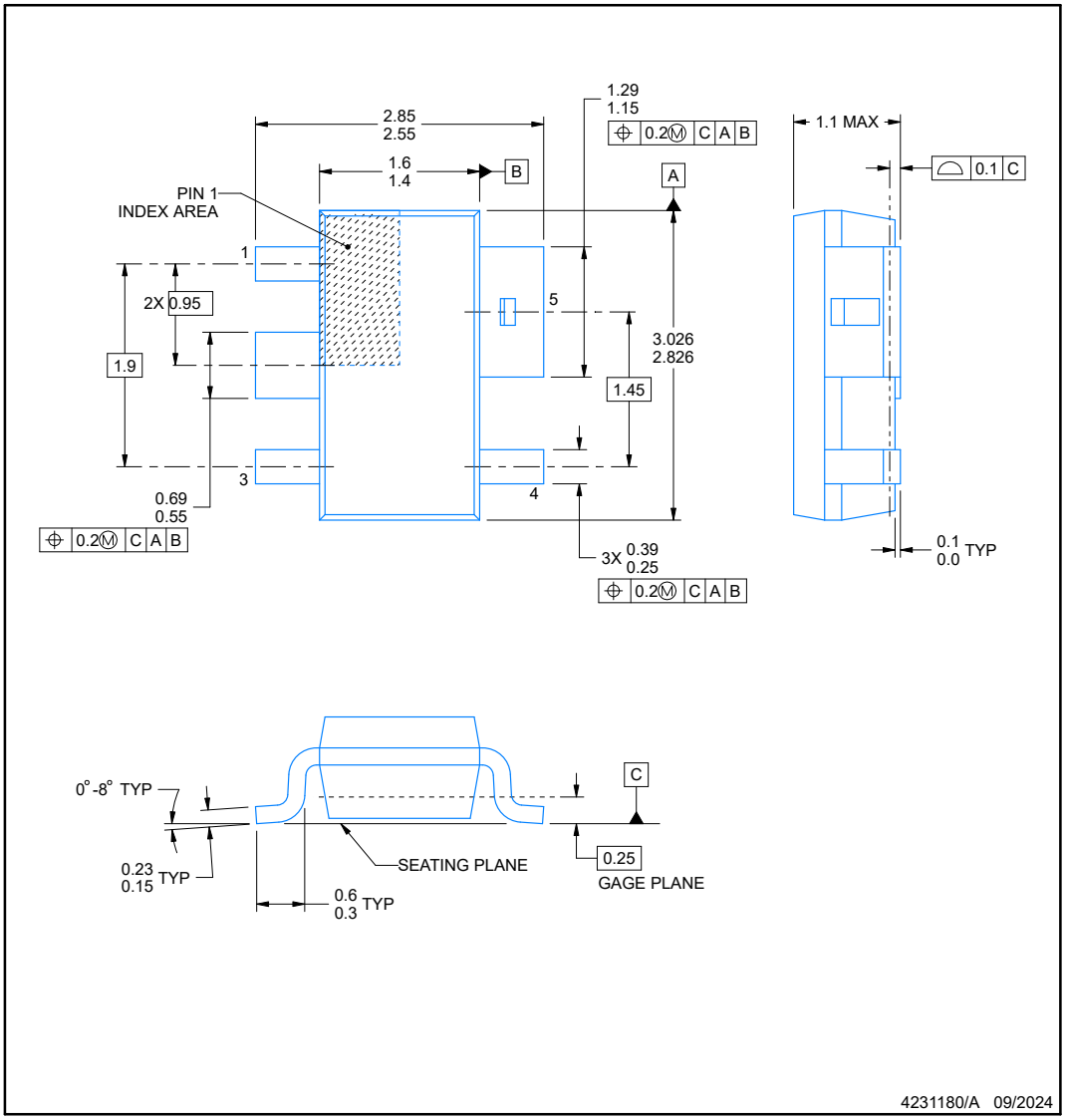
DYB0005A-C01



PACKAGE OUTLINE

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. No JEDEC reference as of August 2020.

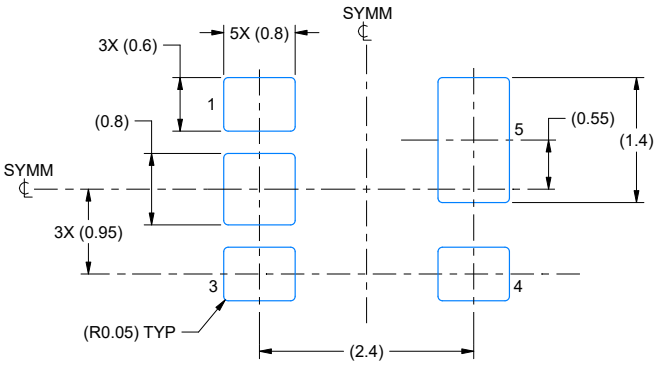
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EXAMPLE BOARD LAYOUT

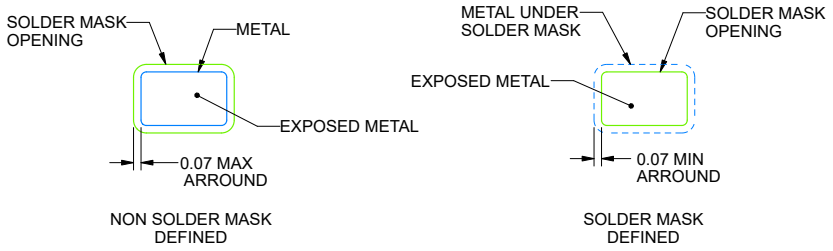
DYB0005A-C01

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPLOSED METAL SHOWN
SCALE:15X



SOLDERMASK DETAILS

4231180/A 09/2024

NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.
5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

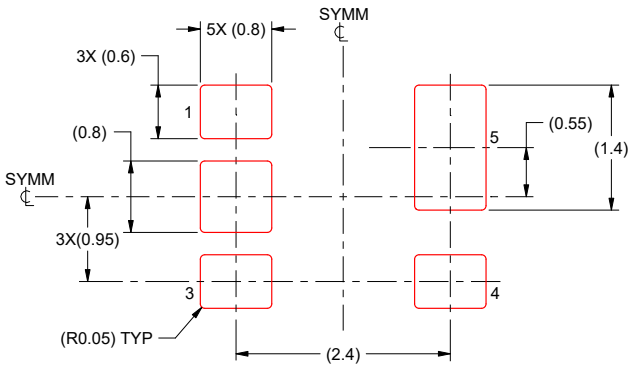
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EXAMPLE STENCIL DESIGN

DYB0005A-C01

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:15X

4231180/A 09/2024

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
7. Board assembly site may have different recommendations for stencil design.

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS7B4255QDBVRQ1	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	2Q5F
TPS7B4255QDBVRQ1.A	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	2Q5F
TPS7B4255QDYBRQ1	Active	Production	SOT-23 (DYB) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2Q6T
TPS7B4255QDYBRQ1.A	Active	Production	SOT-23 (DYB) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2Q6T

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF TPS7B4255-Q1 :

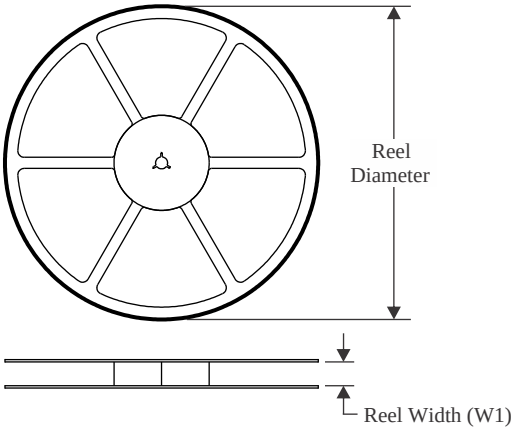
- Catalog : TPS7B4255

NOTE: Qualified Version Definitions:

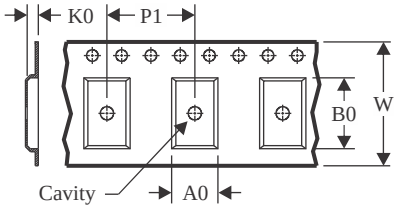
- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION

REEL DIMENSIONS

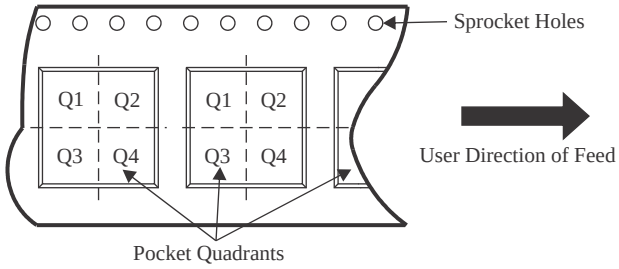


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

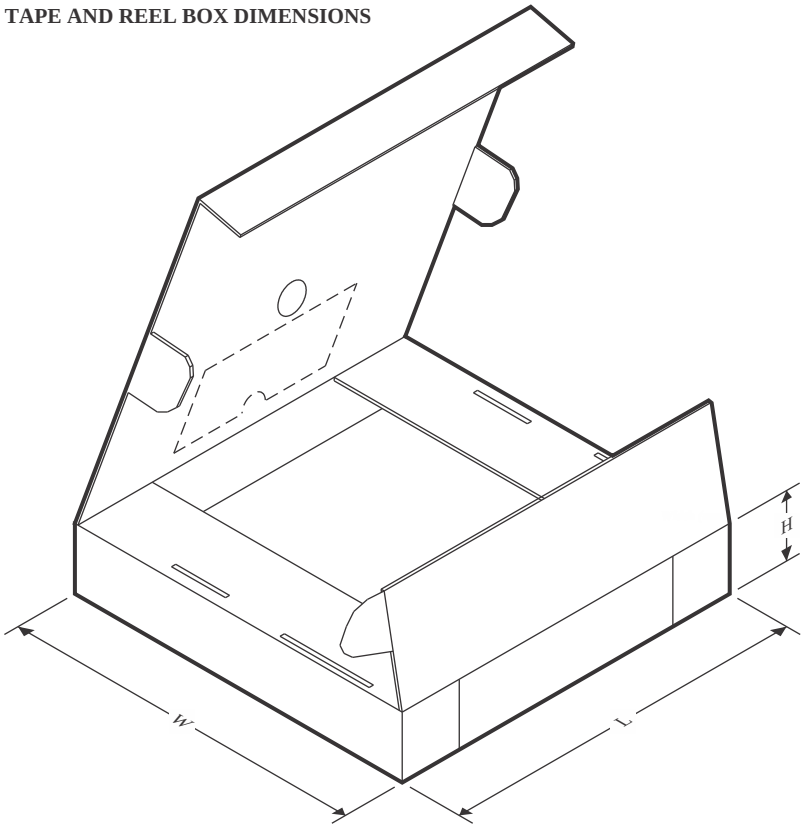
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS7B4255QDBVRQ1	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS7B4255QDYBRQ1	SOT-23	DYB	5	3000	178.0	9.0	3.2	3.05	1.2	4.0	8.0	Q2

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

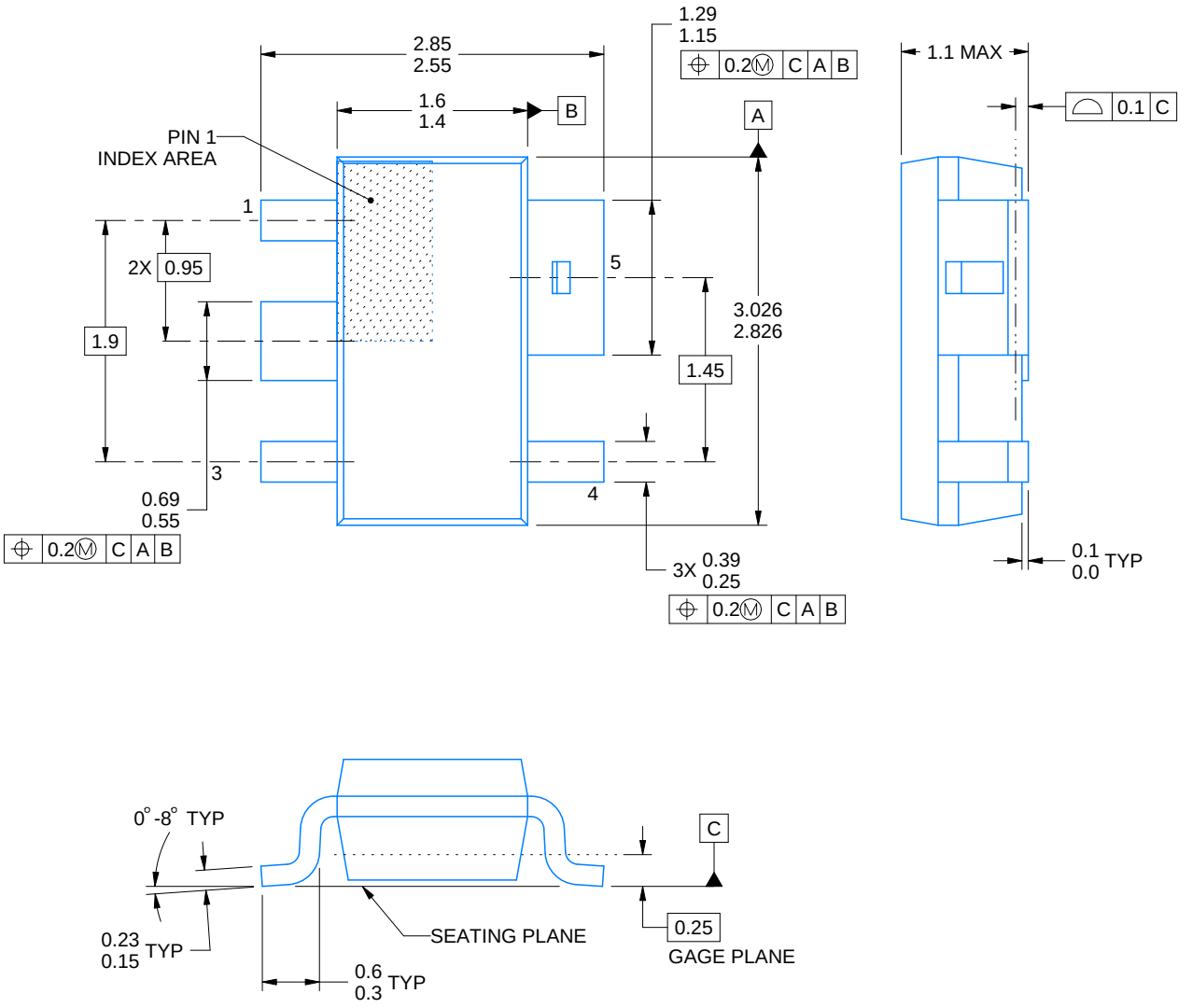
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS7B4255QDBVRQ1	SOT-23	DBV	5	3000	210.0	185.0	35.0
TPS7B4255QDYBRQ1	SOT-23	DYB	5	3000	180.0	180.0	18.0

PACKAGE OUTLINE

DYB0005A

SOT - 1.1 max height

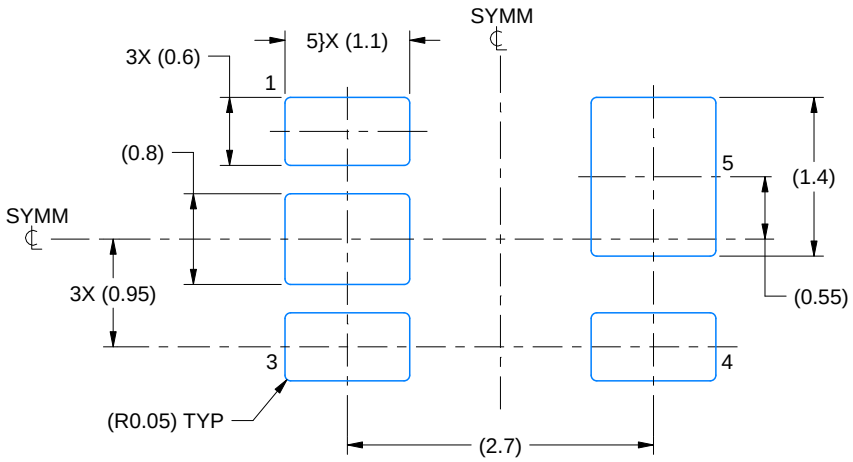
SOT



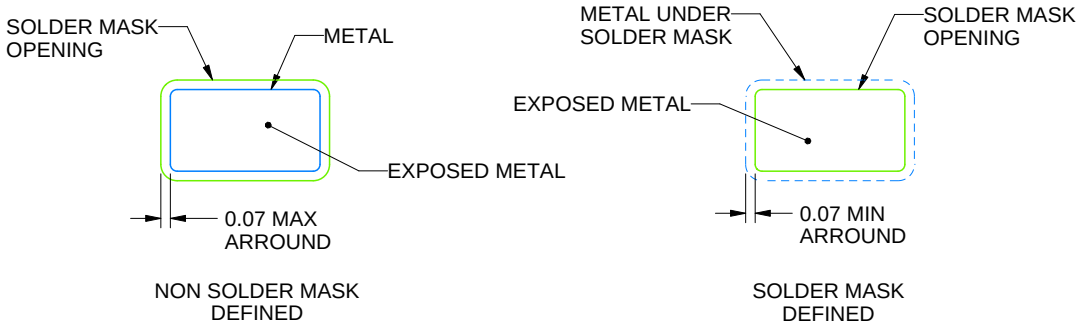
4226199/A 09/2020

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. No JEDEC reference as of August 2020.



LAND PATTERN EXAMPLE
EXPLOSED METAL SHOWN
SCALE:15X

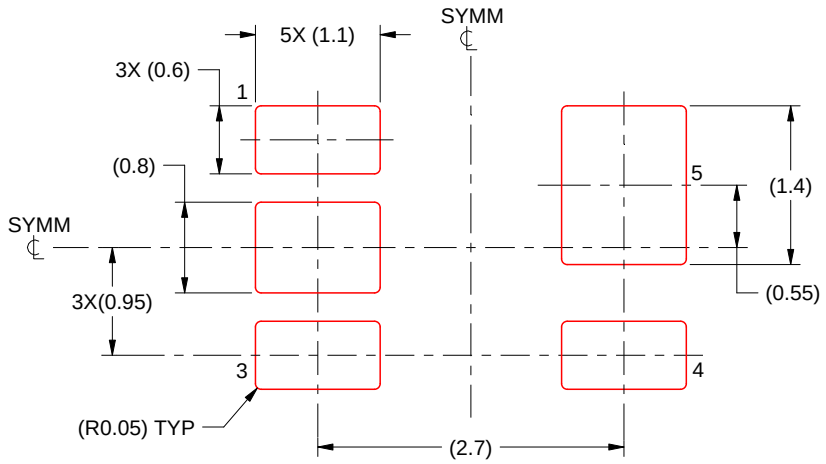


SOLDERMASK DETAILS

4226199/A 09/2020

NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.
5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:15X

4226199/A 09/2020

NOTES: (continued)

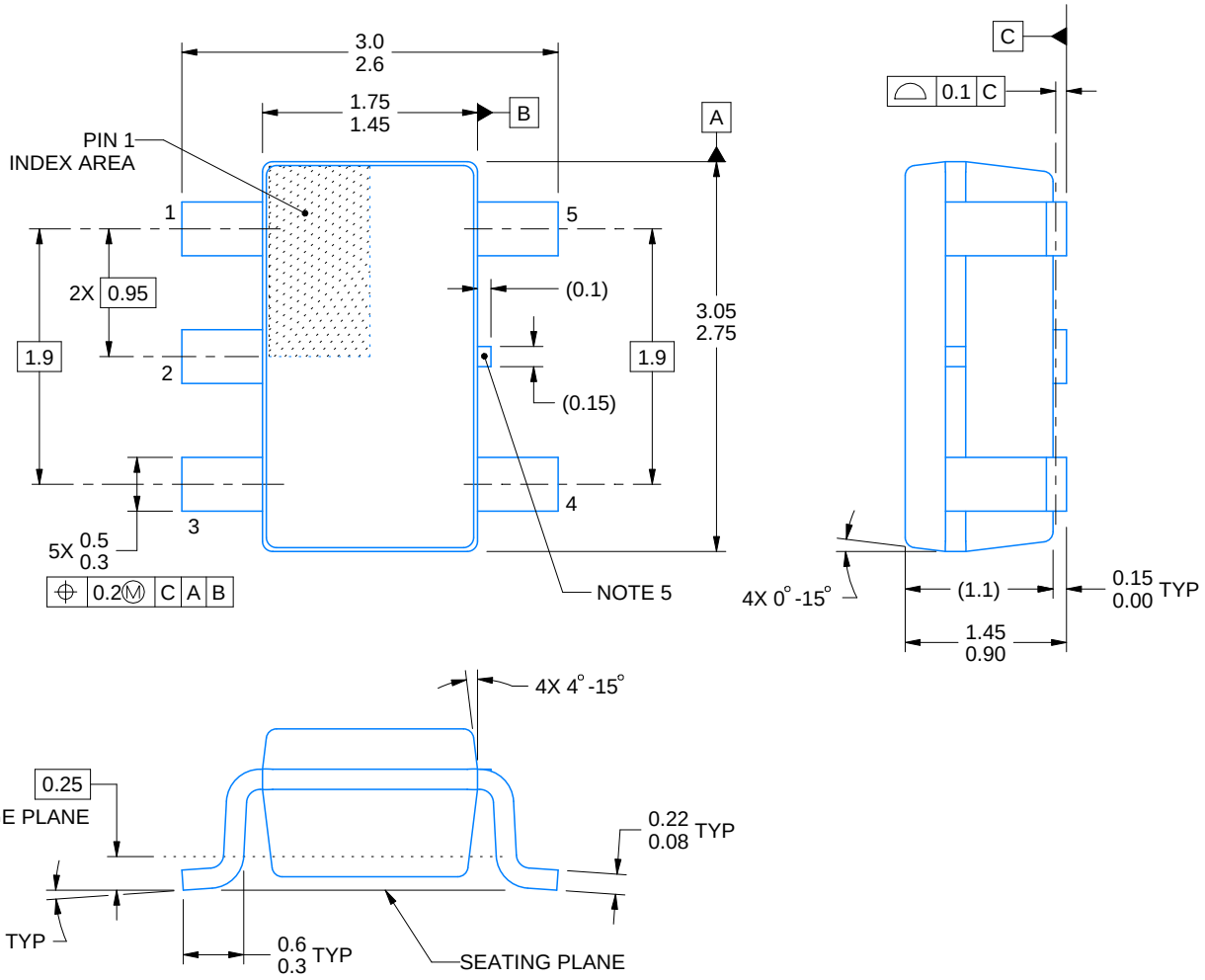
6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
7. Board assembly site may have different recommendations for stencil design.

PACKAGE OUTLINE

DBV0005A

SOT-23 - 1.45 mm max height

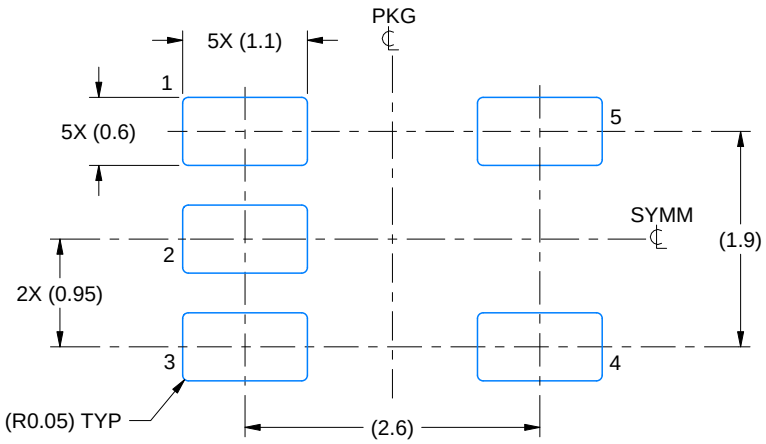
SMALL OUTLINE TRANSISTOR



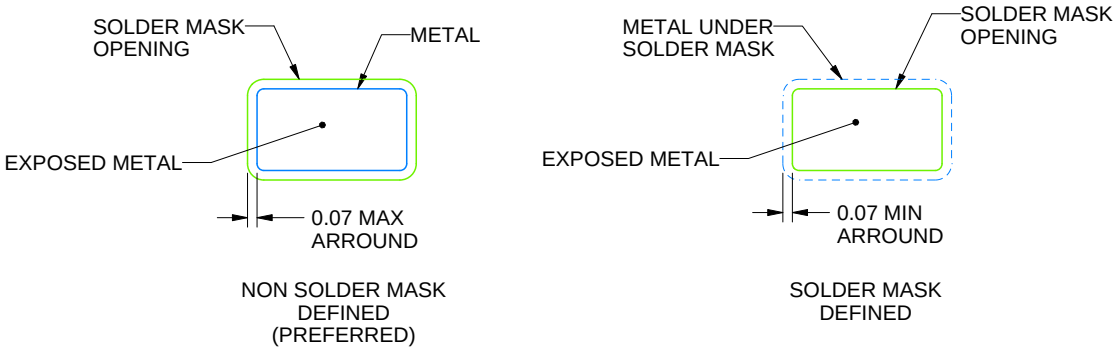
4214839/K 08/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Refernce JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
5. Support pin may differ or may not be present.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X

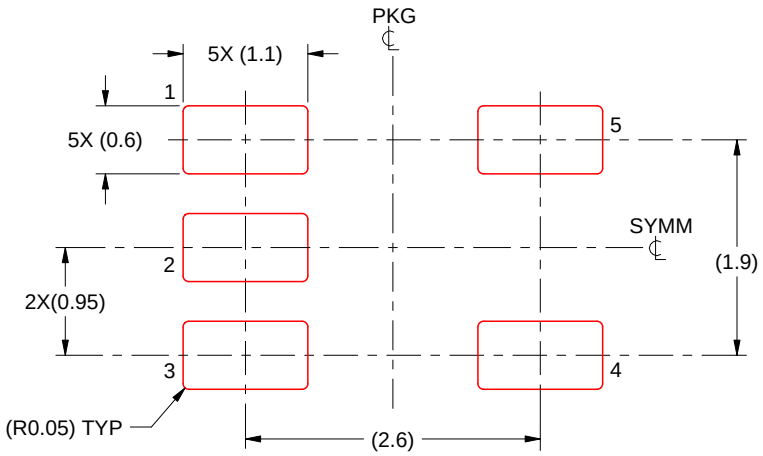


SOLDER MASK DETAILS

4214839/K 08/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/K 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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Last updated 10/2025

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